Monolithic Digital IC

LB11891V



Three-Phase Brushless Motor Driver for Streaming Tape Drives

Overview

The LB11891V is a 3-phase brushless motor driver IC that is optimal for streaming tape drive motors and similar applications.

Functions and Features

- Three-phase full-wave voltage drive (120° voltagelinear drive)
- Torque ripple correction circuit (overlap correction)
- Motor supply voltage control based speed control
- Built-in Hall sensor output FG comparator
- Fixed-phase output function
- Thermal shutdown circuit

Package Dimensions

unit: mm



Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
	V _{CC} 1 max		10	V
Maximum supply voltage	V _{CC} 2 max		11	V
	VS max	$\leq V_{CC}2$	11	V
Maximum applied output voltage	V _O max		VS+2	V
Maximum output current	I _O max		1.0	А
Allowable power dissipation	Pd max	Independent IC	400	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

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Allowable Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
	V _{CC} 1	$V_{CC}1 \leq V_{CC}2$	2.7 to 6.0	V
Supply voltage	V _{CC} 2		3.5 to 9.0	V
	VS		to V _{CC} 2	V
Hall input amplitude	VHALL	Between the Hall sensor inputs	±20 to ±80	mVp-p

Electrical Characteristics at Ta = 25° C, V_{CC}1 = 3 V, V_{CC}2 = 4.75 V, VS = 1.5 V

Deremeter	Symbol	Symbol Conditions		Ratings				
Parameter	Symbol			typ	max			
[Current Drain]								
V _{CC} 1 Current drain	I _{CC} 1	I _{OUT} = 100 mA		5.0	9.0	mA		
V _{CC} 2 Current drain	I _{CC} 2	I _{OUT} = 100 mA		7.0	10.0	mA		
V _{CC} 1 Quiescent current	I _{CC} 1Q	VSTBY = 0 V		3.0	6.0	mA		
V _{CC} 2 Quiescent current	I _{CC} 2Q	VSTBY = 0 V			100	μA		
VS Quiescent current	ISQ	VSTBY = 0 V		75	100	μA		
[VX1]		·						
High side residual voltage	VXH1	I _{OUT} = 0.2 A	0.15	0.22	0.29	V		
Low side residual voltage	VXL1	I _{OUT} = 0.2 A	0.15	0.20	0.25	V		
[VX2]		·						
High side residual voltage	VXH2	I _{OUT} = 0.5 A		0.25	0.40	V		
Low side residual voltage	VXL2	I _{OUT} = 0.5 A		0.25	0.40	V		
Output saturation voltage	V _O sat	I _{OUT} = 0.8 A, Sink + Source			1.40	V		
Amount of overlap	O.L	RL = 39 $\Omega \times 3$, Rangle = 20 k $\Omega *1$	73	80	87	%		
Amount of overlap: difference between high and low sides	Δ0.L	(Average high side overlap amount) - (Average low side overlap amount) *1	-8		+8	%		
[Hall Amplifiers]	•							
Input offset voltage	VHOFF	Design target value *	-5		+5	mV		
Common-mode input range	VHCM	Rangle = 20 k Ω	0.95		2.1	V		
I/O voltage gain	VGVH	Rangle = 20 k Ω	25.5	28.5	31.5	dB		
[Standby Pin]		·						
High-level input voltage	VSTH		2.5			V		
Low-level input voltage	VSTL				0.4	V		
Input current	ISTIN	VSTBY = 3 V		25	40	μA		
Leakage current	ISTLK	VSTBY = 0 V			-30	μA		
[FRC Pin]								
High-level input voltage	VFRCH		2.5			V		
Low-level input voltage	VFRCL				0.4	V		
Input current	IFRCIN	VFRC = 3 V		20	30	μA		
Leakage current	IFRCLK	VFRC = 0 V			-30	μA		
[VH]								
Hall supply voltage	VHALL	IH = 5 mA, VH (+) – VH (–)	0.85	0.95	1.05	V		
Minus (-) pin voltage	VH (–)	IH = 5 mA	0.81	0.88	0.95	V		
*: Design target value parameters ar	e not tested.			Co	ontinued on	next page.		

Note 1. The standard for the overlap amount parameter is to report the measured value without change.

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Deremeter	Question	Operalitions		Linit						
Parameter	Symbol Conditions		min	typ	max	Unit				
[FG Comparator]	[FG Comparator]									
Input hysteresis width 1	VFGHYS1			+10		mV				
Input hysteresis width 2	VFGHYS2			-10		mV				
Low-level output voltage	VFGOL	When the sink current is 0.5 mA		0.2	0.4	V				
High-level output voltage	VFGOH	Pulled up through 10 k Ω internally	V _{CC} 1 - 0.5			V				
Allowable output current	IFGOL				2	mA				
[Lock Pin]	[Lock Pin]									
High-level voltage	VLOH		2.5			V				
Low-level voltage	VLOL				0.4	V				
Input current	VLOIN	VLOCK = 3 V		25		μA				
Leakage current VLOLK		VLOCK = 0 V			-30	μA				
[TSD]										
Thermal shutdown circuit (TSD) operating temperature	T-TSD	Design target value*		180		°C				
TSD temperature hysteresis	ΔTSD	Design target value*		20		°C				

*: Design target value parameters are not tested.



Truth Table

	Course - Cink		Hall input	s	EDC	LOCK	
	Source → Sink	U	V	W	FRC	LUUR	
	$V\toW$		Н		н		
1	$W \rightarrow V$	1 .			L		
	$V \rightarrow U$				Н		
	$U\toV$				L		
	$U\toW$				н		
	$W\toU$	1		L	L		
2	$V \rightarrow W$				Н		
	$W \rightarrow V$				L	Н	
	$U\toV$		L	Н	н		
	$V \rightarrow U$	н			L	L	
3	$U\toW$				Н	н	
	$W\toU$				L		
	$W\toV$		L	Н	н		
	$V \rightarrow W$				L	L	
4	$U\toV$] -			Н	н	
	$V \rightarrow U$				L		
	$W\toU$			н	Н		
5	$U\toW$	1.			L		
5	$W \rightarrow V$] Ľ			Н	ц	
	$V\toW$				L		
	$V\toU$				Н		
	$U\toV$	┨.			L		
0	$ \begin{array}{c} W \rightarrow U \\ U \rightarrow W \end{array} $	н	L	Н	ц		
		1			L	Н	

Note: The "H" entry in the FRC and LOCK columns indicates a voltage of 2.50 V or higher, and the "L" entry indicates a voltage of 0.4 V or lower. (When V_{CC}1 is 3 V)

Note: For the Hall sensor inputs, the input "H" state is a state where the + input is at least 0.02 V higher than the - input, and the input "L" state is a state where the + input is at least 0.02 V lower than the – input.

Pin Assignments



Block Diagram





Overlap Creation and Calculations

Overlap Creation

For the voltages generated in the control block, if the midpoint is taken as the reference, one side will be $\begin{pmatrix} 1 \\ 1 \end{pmatrix}$

$$2 \times \text{O.L.} \times \left(\frac{1}{2} \text{VS} - \text{VX}\right)$$
.

Therefore, the waveform crossover will be O.L. $\times \left(\frac{1}{2} VS - VX\right)$ from the midpoint.

Since that waveform is clamped at $\left(\frac{1}{2}VS - VX\right)$ referenced to the midpoint, the overlap will be: $\frac{A}{B} \times 100 = O.L. \times 100$ [%].

Overlap Calculation

(1) High side overlap

The calculated midpoint is
$$VN = \frac{(VS - VXH - VXL)}{2} + VXL = \frac{VS - VXH - VXL}{2}$$

Since $A = \alpha - VN$ and B = VS - VXH - VN, the high side overlap can be calculated as follows.

$$Overlap = \frac{A}{B} = \frac{V\alpha - ((VS - VXH + VXL)/2)}{VS - VXH - ((VS - VXH + VXL)/2)} \times 100 = \frac{2V\alpha - ((VS - VXH) - VXL)}{(VS - VXH - VXL)} \times 100 [\%]$$

(2) Low side overlap

Since $C = VN - V\beta$ and D = VN - VXL, the low side overlap can be calculated as follows.

$$Overlap = \frac{C}{D} = \frac{((VS - VXH + VXL)/2) - V\beta}{((VS - VXH + VXL)/2) - VXL} \times 100 = \frac{(VS - VXH) + VXL - 2V\beta}{(VS - VXH) - VXL} \times 100 \ [\%].$$



Application Circuit Example

Pin Functions and Equivalent Circuits

Pin No.	Symbol	Voltage	Function	Equivalent circuit
16 17 18 19 20 21	$U_{IN}1$ $U_{IN}2$ $V_{IN}1$ $V_{IN}2$ $W_{IN}1$ $W_{IN}2$	0 to V _{CC} 1	Capstan motor driver U, V, and W phase Hall effect sensor inputs. The logic high state indicates that IN1 > IN2.	V_{CC1}
12	ANGLE		Controls the gain from the Hall inputs to the output. The gain is controlled by the resistor inserted between this pin and ground.	$\begin{array}{c} & & & & \\ & & & & \\ & & & \\ & & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ &$
3	VS	0 to V _{CC} 2	Power supply that determines the amplitude of the output to the capstan motor. This voltage must be lower than $V_{\rm CC}2.$	1/4*VS
5 7 9 6, 8	U-OUT V-OUT W-OUT Rf		Capstan motor driver U, V, and W phase outputs.	
10	VH+	The Ha	The Hall effect sensor element bias voltage supply. A voltage of 0.85 V	
11	VH-		(typical) is generated between the VH+ and VH– pins. (When IH is 5 mA)	
22	FG1		Comparator output for U_{IN} 1 and U_{IN} 2.	
23	FG2		Comparator output for V_{IN} 1 and V_{IN} 2.	
24	FG		Three-phase synthesized output for the U, V, and W phase comparator output.	

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Pin No.	Symbol	Voltage	Function	Equivalent circuit	
14	FRC	0 to Vee1	Capstan motor forward/reverse control. This pin determines the direction (forward or reverse) of the capstan motor. (This input has hysteresis characteristics.)		
15	STBY	0 to V _{CC} 1		Selects the bias supply for all the capstan motor circuits other than the FG comparator. Setting this pin low cuts off the bias supply. Thus it functions as the standby mode control pin.	
4	LOCK	0 to V _{CC} 1	The output phase is locked by applying a low to high trigger voltage (edge) to this pin. This prevents the motor from turning due to the application of an external load in the motor stopped state.	4 100 kΩ 100 kΩ	
2	V _{CC} 2	3.5 to 6 V	Power supply used for the source side pre-driver voltage and the coil waveform detection comparator.		
1	V _{CC} 1	2.7 to 6 V	Power supply used for voltages other than the motor voltage, the source side pre-driver voltage, and the coil waveform detection comparator.		
13	GND		Ground used for all systems other than the output system.		

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